

Vishay Siliconix

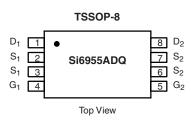
## **Dual P-Channel 30-V (D-S) MOSFET**

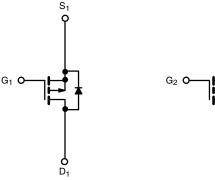
PRODUCT SUMMARY					
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω)	I <sub>D</sub> (A)			
- 30	0.080 at V <sub>GS</sub> = - 10 V	± 2.9			
	0.135 at V <sub>GS</sub> = - 4.5 V	± 2.2			

#### FEATURES

- Halogen-free
- TrenchFET<sup>®</sup> Power MOSFETs







D<sub>2</sub> P-Channel MOSFET

 $S_2$ 

**Ordering Information:** Si6955ADQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T<sub>A</sub> = 25 °C, unless otherwise noted Symbol **Steady State** Parameter 10 s Unit Drain-Source Voltage V<sub>DS</sub> - 30 V ± 20 Gate-Source Voltage V<sub>GS</sub> T<sub>A</sub> = 25 °C ± 2.5 ± 2.9 Continuous Drain Current  $(T_J = 150 \ ^{\circ}C)^a$  $\mathsf{I}_\mathsf{D}$ T<sub>Δ</sub> = 70 °C ± 2.3 ± 2.0 А Pulsed Drain Current (10 µs Pulse Width) I<sub>DM</sub> ± 20 - 1.0 - 0.70  $I_S$ Continuous Source Current (Diode Conduction)<sup>a</sup> T<sub>A</sub> = 25 °C 1.14 0.83  $P_D$ W Maximum Power Dissipation<sup>a</sup> T<sub>A</sub> = 70 °C 0.53 0.73 °C Operating Junction and Storage Temperature Range T<sub>J</sub>, T<sub>stg</sub> - 55 to 150

THERMAL RESISTANCE RATINGS								
Parameter		Symbol	Typical	Maximum	Unit			
	t ≤ 10 s	- R <sub>thJA</sub> R <sub>thJF</sub>	88	110				
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		124	150	°C/W			
Maximum Junction-to-Foot	Steady State		69	83				

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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<b>SPECIFICATIONS</b> $T_J = 25 \circ C$ Parameter	Symbol	Test Conditions		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -24 V, V_{GS} = 0 V$			- 1		
		$V_{DS}$ = - 24 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C		- 10	μA		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \geq$ - 5 V, $V_{GS}$ = - 10 V	- 15			А	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 10 V, I <sub>D</sub> = - 2.9 A		0.062	0.080	Ω	
		$V_{GS}$ = - 4.5 V, $I_D$ = - 2.2 A		0.105	0.135		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 15 V, I <sub>D</sub> = - 2.9 A		5		S	
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 1.0 A, V <sub>GS</sub> = 0 V		- 0.82	- 1.2	V	
Dynamic <sup>b</sup>			•				
Total Gate Charge	Qg			5.8	8	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 10 V, $V_{GS}$ = - 5 V, $I_{D}$ = - 2.9 A		2			
Gate-Drain Charge	Q <sub>gd</sub>			1.9			
Turn-On Delay Time	t <sub>d(on)</sub>			8	15		
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 10 V, $R_L$ = 10 $\Omega$		9	18	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D$ $\cong$ - 1 A, $V_{GEN}$ = - 10 V, $R_G$ = 6 $\Omega$		21	40		
Fall Time	t <sub>f</sub>			10	20		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = - 1.0 A, dl/dt = 100 A/μs		30	50		

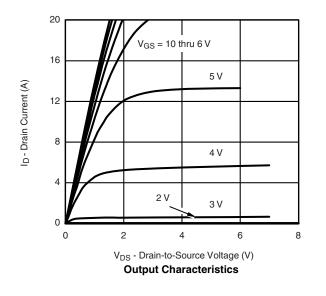
Notes:

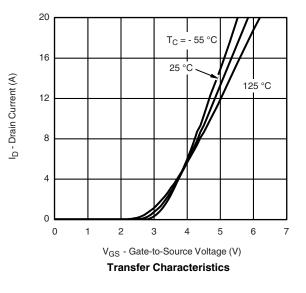
a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



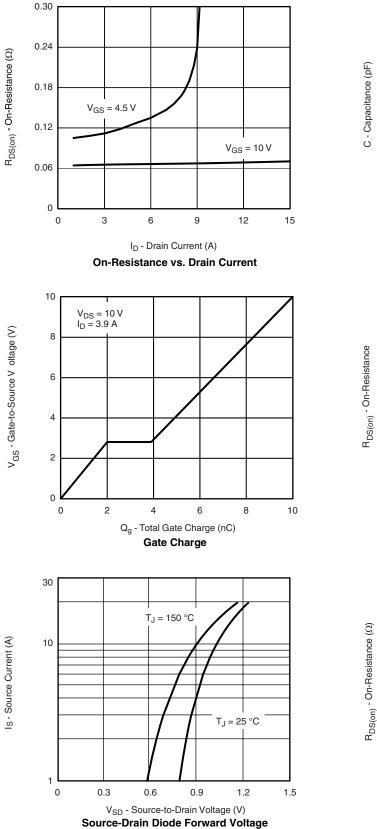


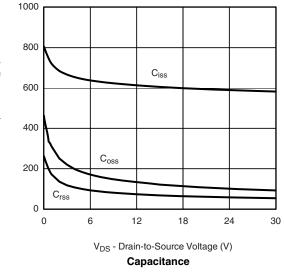


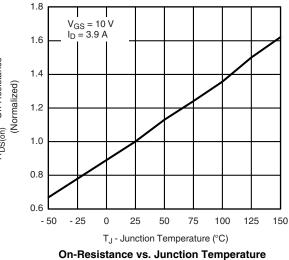
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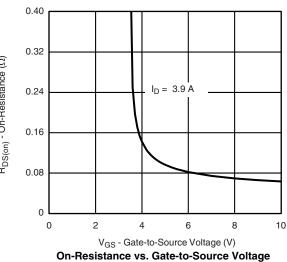
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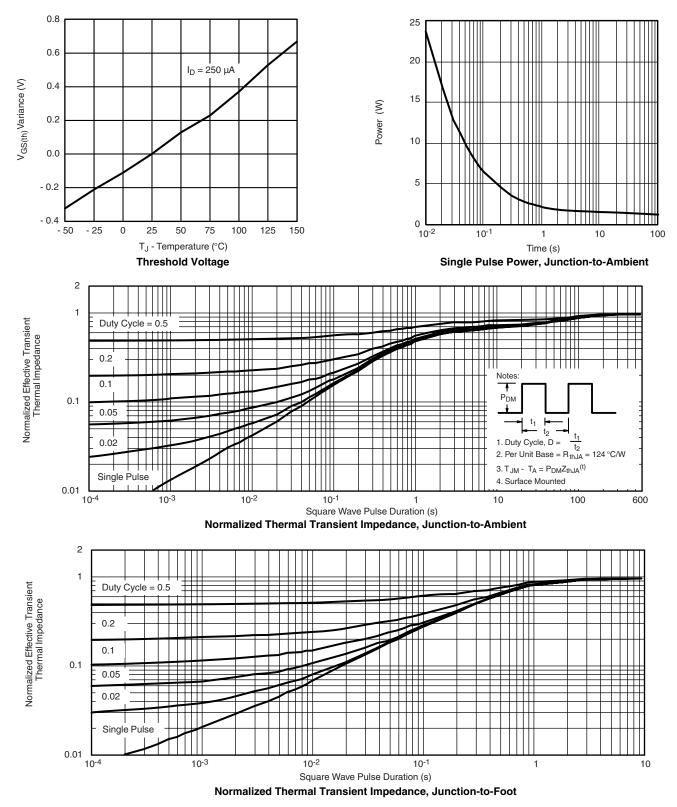


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